

Title (en)

AMORPHOUS SILICON PHOTORECEPTORS FOR ELECTROPHOTOGRAPHY, PROCESS FOR THE PREPARATION AND/OR REGENERATION THEREOF, AND METHOD FOR THE ELECTROPHOTOGRAPHY USING SUCH MATERIALS

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Application

EP 86104635 A 19860404

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- JP 26454685 A 19851125
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Abstract (en)

[origin: EP0198363A2] An amorphous silicon photoreceptor for electrophotography having a specific surface roughness is disclosed herein. Also provided are a process for the preparation and/or regeneration of the material and improved methods for electrophotography, which use a special abrasive. The material enables the electrophotography without occurrence of any image blurring under high humidity conditions.

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Citation (search report)

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- [XP] PATENT ABSTRACTS OF JAPAN, vol. 9, no. 122 (P-359)[1845], 28th May 1985; & JP-A-60 007 433 (STANLEY DENKI K.K.) 16-01-1985

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